CMPD2836 CMPD2838

SURFACE MOUNT DUAL, SILICON SWITCHING DIODES



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMPD2836 and CMPD2838 types are ultra-high speed switching diodes manufactured by the epitaxial planar process, in an epoxy molded surface mount package, designed for high speed switching applications.



The following configurations are available:

CMPD2836 DUAL, COMMON ANODECMPD2838 DUAL, COMMON CATHODEMARKING CODE: CA6

MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	75	V
Average Forward Current	IO	200	mA
Peak Forward Current	I _{FM}	300	mA
Power Dissipation	P_{D}	350	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JA}	357	°C/W

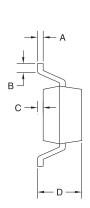
ELECTRICAL CHARACTERISTICS PER DIODE: (TA=25°C unless otherwise noted) **TEST CONDITIONS** UNITS SYMBOL MIN MAX I_R $V_R = 50V$ 100 nΑ BV_R I_R=100μA 75 ٧ ٧F I_F=10mA 1.0 V_{F} I_F=50mA 1.0 I_F=100mA V_{F} 1.2 V V_R=0, f=1.0MHz 4.0 C_{T} 1.5 рF $I_R = I_F = 10 \text{mA}$, $R_L = 100 \Omega$, Rec. to 1.0 mA 4.0 ns t_{rr}

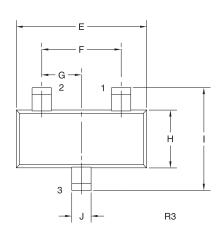
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SOT-23 CASE - MECHANICAL OUTLINE

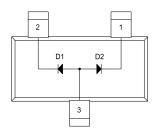




DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
Α	0.003	0.007	0.08	0.18		
В	0.006	-	0.15	-		
С	-	0.005	-	0.13		
D	0.035	0.043	0.89	1.09		
Е	0.110	0.120	2.80	3.05		
F	0.075		1.90			
G	0.037		0.95			
Н	0.047	0.055	1.19	1.40		
	0.083	0.098	2.10	2.49		
J	0.014	0.020	0.35	0.50		

SOT-23 (REV: R3)

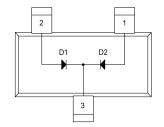
PIN CONFIGURATIONS



CMPD2836

- **LEAD CODE:**1) Cathode D2
- 2) Cathode D1
- 3) Anode D1, D2

MARKING CODE: CA2



CMPD2838

LEAD CODE:

- 1) Anode D2
- 2) Anode D1
- 3) Cathode D1, D2

MARKING CODE: CA6

R6 (25-January 2010)

Mouser Electronics

Authorized Distributor

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Central Semiconductor: CMPD2836 TR PBFREE